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Correction: Sodium doping for enhanced performance by highly efficient CsPbBr₃ quantum dot-based electroluminescent light-emitting diodes

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Correction for 'Sodium doping for enhanced performance by highly efficient CsPbBr₃ quantum dot-based electroluminescent light-emitting diodes' by Yi Huang *et al.*, *J. Mater. Chem. C*, 2022, DOI: 10.1039/d1tc05997a.

The authors regret an error in Fig. 7 in the published article, where Fig. 7b (current density–voltage plot) was accidentally replaced with a duplicate of Fig. 7d. The correct version of Fig. 7 is shown here.

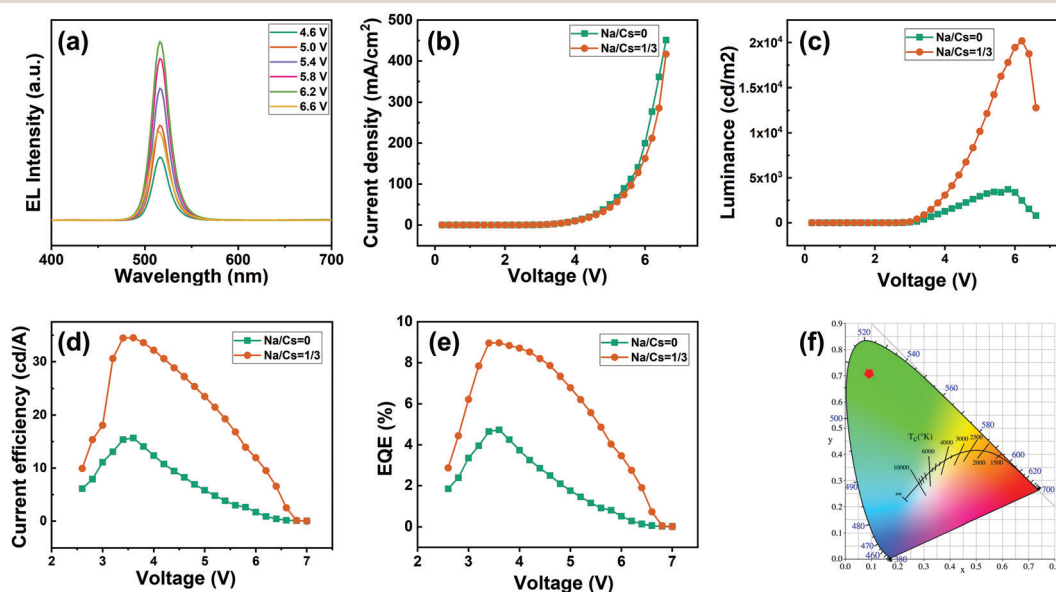


Fig. 7 (a) EL spectra of the Na⁺-doped CsPbBr₃ QD-based QLED device under different driving voltages. (b) Current density–voltage, (c) luminance–voltage, (d) current efficiency–voltage, and (e) EQE–voltage plots of the QLED device with undoped and Na⁺-doped CsPbBr₃ QDs as the emitting layer. (f) The chromaticity coordinates of the corresponding Na⁺-doped CsPbBr₃ QLED device.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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